OSRAM LZ4-00UBH0 **Datasheet**

Preliminary datasheet version





LED ENGIN LuxiGen

LZ4-00UBH0

Industry most robust high power ceramic package with glass lens for high performance over life.









Applications

- Agriculture & Horticulture
- Appliances & Tools
- Entertainment

- Material Processing
- Medical Lighting

Features

- Package: Ceramic package with integrated glass lens
- Chip technology: UX:3
- Typ. Radiation: 120°
- Color: λ_{peak} = 395 nm (• violet)

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Ordering Information			
Туре	Total radiant flux ¹⁾ $I_F = 700 \text{ mA}$ Φ_E	Ordering Code	
LZ4-00UBH0-00U4	4.8 7.5 W	Q65113A4212	
LZ4-00UBH0-00U5	4.8 7.5 W	Q65113A4211	
LZ4-00UBH0-00U8	4.8 7.5 W	Q65113A4209	

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Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	T _{op}	min.	-30 °C
		max.	70 °C
Storage Temperature	T _{stg}	min.	-40 °C
	-19	max.	125 °C
Junction Temperature 2)	T _j	max.	76 °C
Forward Current 2)	I _F	max.	900 mA
Forward Current pulsed	I _{F pulse}	max.	1000 mA
$t \le 10 \text{ ms}; D \le 0.1; T_{c} = 25 ^{\circ}\text{C}$			
ESD withstand voltage	$V_{\scriptscriptstyle{ESD}}$		ESD sensitive device
acc. ANSI/ESDA/JEDEC JS-001 (HBM, Class 0)			
Reverse voltage 3)	V_R		Not designed for
			reverse operation

Characteristics

 $\rm I_{\scriptscriptstyle F}$ = 700 mA; $\rm T_{\scriptscriptstyle C}$ = 25 °C; all chips operated in series

Parameter	Symbol		Values
Total radiant flux 4)	Φ_{E}	typ.	5.9 W
Peak Wavelength 5)	λ_{peak}	min.	385 nm
$I_{\rm F} = 700 \text{mA}$	poun	typ.	395 nm
		max.	410 nm
Viewing angle at 50% I _v	2φ	typ.	110 °
Forward Voltage 6)4)	V _F	min.	12.8 V
$I_{\rm F} = 700 \text{mA}$	•	typ.	14.2 V
		max.	16.8 V
Reverse current 3)	I _R		Not designed
			for reverse
			operation
Electrical thermal resistance junction/case	$R_{ ext{thJC elec.}}$	typ.	0.50 K / W

Brightness Groups

all chips operated in series

Group	Total radiant flux 1)	Total radiant flux 1)	
	$I_{F} = 700 \text{ mA}$	I _F = 700 mA	
	min.	max.	
	Φ_{E}	Φ_{E}	
U	4.8 W	6.0 W	
V	6.0 W	7.5 W	

Wavelength Groups

all chips operated in series

Group	Peak Wavelength ⁵⁾ I _F = 700 mA min.	Peak Wavelength ⁵⁾ I _F = 700 mA max.	
	λ_{peak}	$\lambda_{\sf peak}$	
U4	385 nm	390 nm	
U5	390 nm	395 nm	
U8	405 nm	410 nm	

Group Name on Label

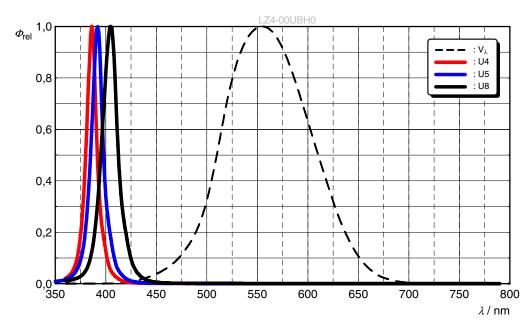
Example: U-U4

Brightness Wavelength

U U4

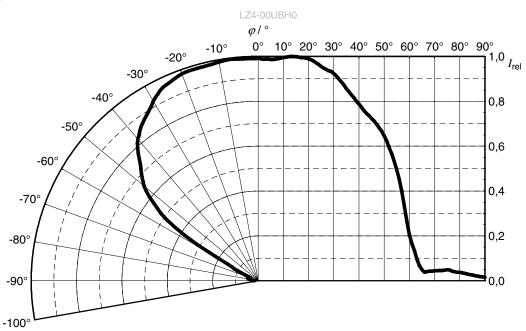
Relative Spectral Emission 4)

$$\Phi_{rel}$$
 = f (λ); I_F = 700 mA; T_C = 25 °C



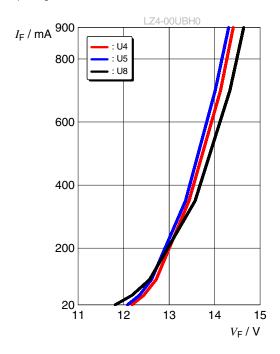
Radiation Characteristics 4)

 $I_{rel} = f(\phi); T_C = 25 °C$



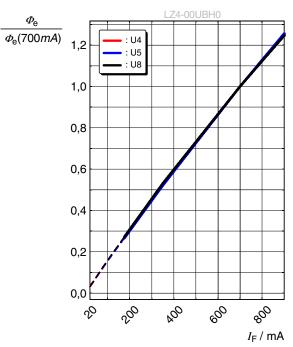
Forward current 4)

$$I_F = f(V_F); T_C = 25 \, ^{\circ}C$$



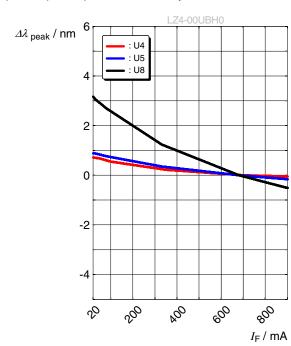
Relative Radiant Power 4), 7)

$$\Phi_{\rm E}/\Phi_{\rm E}(700~{\rm mA})$$
 = f(I_F); T_C = 25 °C



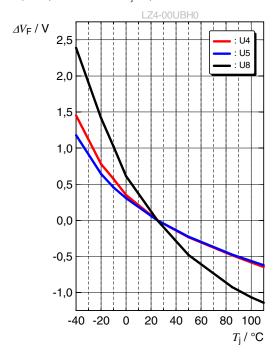
Peak Wavelength 4)

$$\Delta\lambda_{\text{peak}} = \lambda_{\text{peak}} - \lambda_{\text{peak}} (25 \text{ °C}) = f(T_j); I_F = 700 \text{ mA}$$



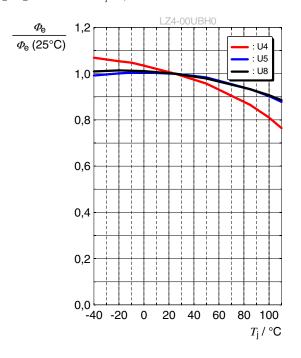
Forward Voltage 4)

$$\Delta V_F = V_F - V_F (25 \ ^{\circ}C) = f(T_j); I_F = 700 \ mA$$



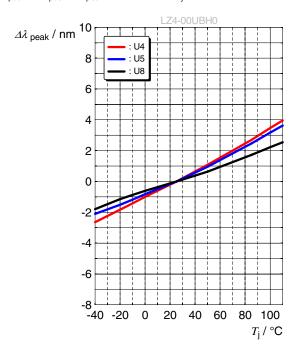
Relative Radiant Power 4)

$$\Phi_{\rm E}/\Phi_{\rm E}(25~{\rm ^{\circ}C}) = f(T_{\rm i}); I_{\rm E} = 700~{\rm mA}$$



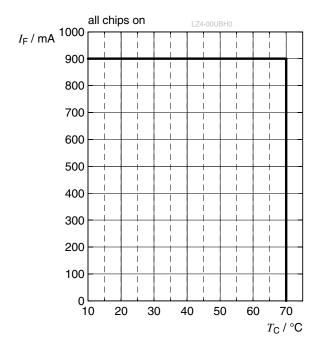
Peak Wavelength 4)

$$\Delta\lambda_{\text{peak}} = \lambda_{\text{peak}} - \lambda_{\text{peak}} (25 \text{ °C}) = f(T_j); I_F = 700 \text{ mA}$$

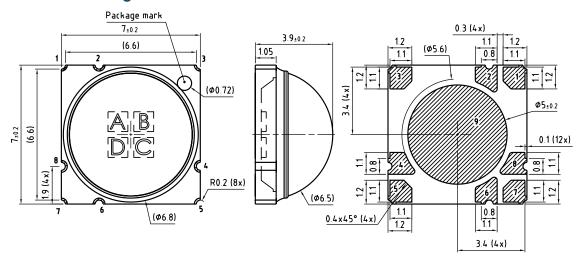


Max. Permissible Forward Current

 $I_F = f(T)$



Dimensional Drawing 8)



General tolerance ±0.1
Pad finish silver

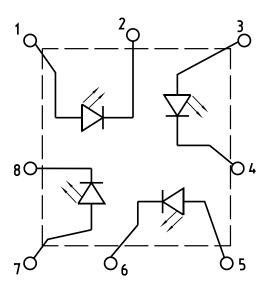
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Further Information:

Approximate Weight: 263.0 mg

Electrical Internal Circuit

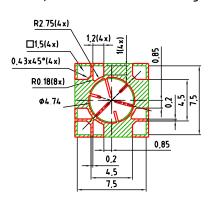
	Pin Out		
Pad	Die	Function	
1	Α	Anode	
2	Α	Cathode	
3	В	Anode	
4	В	Cathode	
5	C	Anode	
6	C	Cathode	
7	D	Anode	
8	D	Cathode	
9	n/a	Thermal	

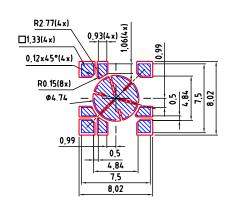


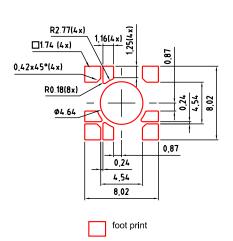
Recommended Solder Pad 8)

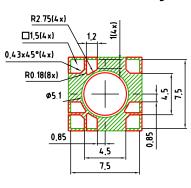
1,16(4x) 1,25(4x) R2.77(4x) □1.74 (4 x) 0.42×45°(4×) R0.18(8x 0.24 Ø0 75 ø5 Ø2.5 0.87 0,24 4.54 8 02

Non-pedestal MCPCB Design

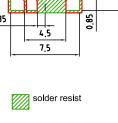


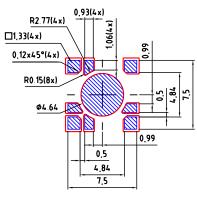






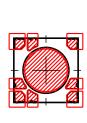
Pedestal MCPCB Design

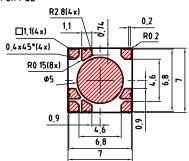






Component Location on Pad



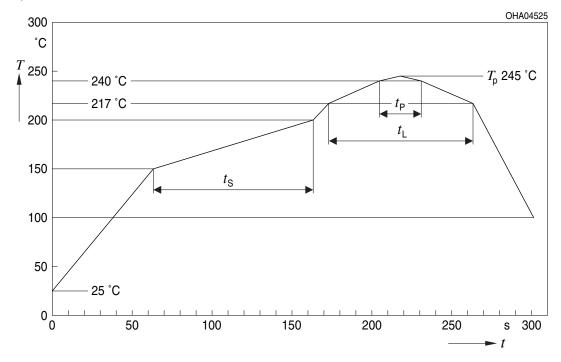


E062.3010.291-01

- 1. For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere.
- 2. Package not suitable for ultra sonic cleaning.
- 3. Pedestal MCPCB allows the emitter thermal slug to be soldered directly to the metal core of the MCPCB. Such MCPCB eliminate the high thermal resistance dielectric layer that standard MCPCB technologies use in between the emitter thermal slug and the metal core of the MCPCB, thus lowering the overall system thermal resistance.
- 4. X-ray sample monitoring for solder voids underneath the emitter thermal slug is recommended. The total area covered by solder voids should be less than 20% of the total emitter thermal slug area. Excessive solder voids will increase the emitter to MCPCB thermal resistance and may lead to higher failure rates due to thermal over stress.

Reflow Soldering Profile

Product complies to MSL Level 1 acc. to JEDEC J-STD-020E

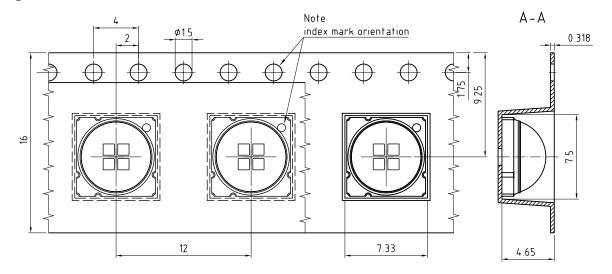


Profile Feature	Symbol	Pb-Free (S	Pb-Free (SnAgCu) Assembly		
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*)	'		2	3	K/s
25 °C to 150 °C					
Time t _s	t_s	60	100	120	S
T_{Smin} to T_{Smax}					
Ramp-up rate to peak*)			2	3	K/s
T_{Smax} to T_{P}					
Liquidus temperature	T_L		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	T _P		245	250	°C
Time within 5 °C of the specified peak temperature T _P - 5 K	t _P	10	20	30	S
Ramp-down rate* T _p to 100 °C			3	4	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the component

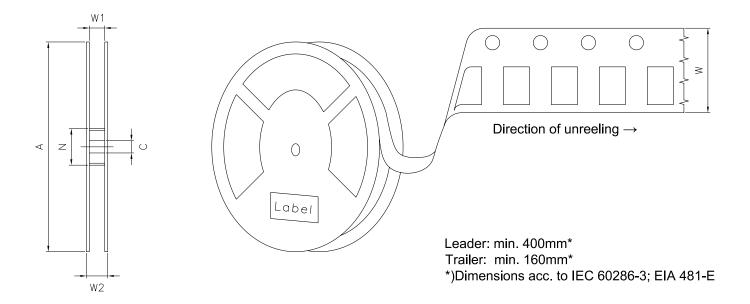
^{*} slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

Taping 8)



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Tape and Reel 9)



Reel Dimensions

Α	W	N_{\min}	W_1	$W_{2\text{max}}$	Pieces per PU
180 mm	16 + 0.3 / - 0.1 mm	60/100 mm	16.4 + 2 mm	22.4 mm	250

OSRAM

Opto Semiconductors

Our Brand

LED ENGIN

(6P) Batch No: 1234567890 (1T) Lot No: 1234567890 (X) Prod No: 12345678

(9D) D/C: 1234

(Q) Qty: 9999

CoO: XX

LXX-XXXXX BIN1: XXX-X-X-XXX BIN2: XXX-X-X-XXX

XxxXxx BIN3: XX-X-X-XXX

RoHS Compliant BIN4: XXX-XXX-X-XXX

BIN5: X-XX-X-XXX

BIN6: X-XX-X-XXX

ML TEMP ST

Pack: RXX

B X123 12345.1234

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Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class high risk (exposure time less then 0.25 s). Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

Tapes and reels are shipped in airtight bags in order to reduce the onset of silver tarnish. We recommend bags only be opened when ready to use emitters. Partially used reels or trays should be stored in airtight bags or in storage purged with nitrogen.

Based on very short life cycle times in chip technology this component is subject to frequent adaption to the latest chip technology.

Changes to the content of this datasheet may occur without further notification. JEDEC 46C constitutes the guideline of the change management for the device specified in this document.

For further application related information please visit www.osram-os.com/appnotes



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Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer - or customer supplied by buyer - considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



Glossary

- Brightness: Brightness groups are tested at a current pulse duration of 10 ms and a tolerance of ±10 %.
- 2) Operating Conditions: Operating conditions according DC-derating (Max. Permissible Forward Current)
- 3) Reverse Operation: Not designed for reverse operation. Continuous reverse operation can cause migration and damage of the device.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- Peak Wavelength: Wavelengths are tested at a current pulse duration of 10 ms and a tolerance of ±2 nm.
- 6) Forward Voltage: Forward voltages are tested at a current pulse duration of 10 ms and a tolerance of ±0.1 V.
- Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- 9) Tape and Reel: All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.

Revision History			
Version	Date	Change	
0.1	2022-08-30	Initial Version	



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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